# features

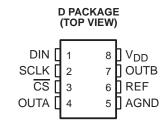
- Dual 10-Bit Voltage Output DAC
- Programmable Settling Time
  2.5 μs in Fast Mode
  12 μs in Slow Mode
- Compatible With TMS320 and SPI<sup>™</sup> Serial Ports
- Differential Nonlinearity <0.2 LSB Typ
- Monotonic Over Temperature

#### description

The TLV5617A is a dual 10-bit voltage output DAC with a flexible 3-wire serial interface. The serial interface is compatible with TMS320, SPI<sup>™</sup>, QSPI<sup>™</sup>, and Microwire<sup>™</sup> serial ports. It is programmed with a 16-bit serial string containing 4 control and 10 data bits.

#### applications

- Digital Servo Control Loops
- Digital Offset and Gain Adjustment
- Industrial Process Control
- Machine and Motion Control Devices
- Mass Storage Devices



The resistor string output voltage is buffered by an x2 gain rail-to-rail output buffer. The buffer features a Class-AB output stage to improve stability and reduce settling time. The programmable settling time of the DAC allows the designer to optimize speed versus power dissipation.

Implemented with a CMOS process, the device is designed for single supply operation from 2.7 V to 5.5 V. It is available in an 8-pin SOIC package in standard commercial and industrial temperature ranges.

|               | PACKAGE     |
|---------------|-------------|
| TA            | SOIC<br>(D) |
| 0°C to 70°C   | TLV5617ACD  |
| -40°C to 85°C | TLV5617AID  |

#### AVAILABLE OPTIONS



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

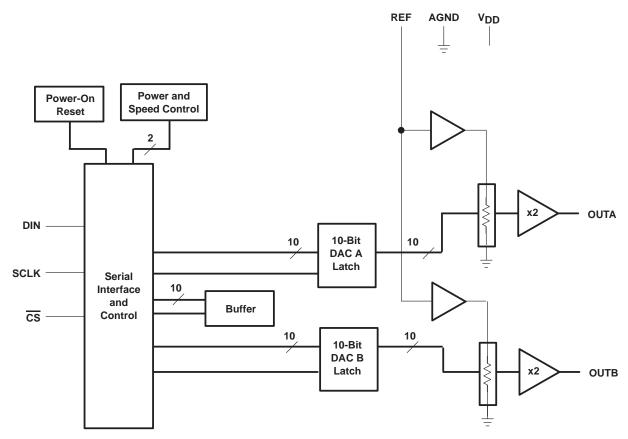
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# functional block diagram



# **Terminal Functions**

| TERM            | NAL | I/O/P | DESCRIPTION                                                           |
|-----------------|-----|-------|-----------------------------------------------------------------------|
| NAME            | NO. | 1/0/P | DESCRIPTION                                                           |
| AGND            | 5   | Р     | Ground                                                                |
| CS              | 3   | Ι     | Chip select. Digital input active low, used to enable/disable inputs. |
| DIN             | 1   | Ι     | Digital serial data input                                             |
| OUTA            | 4   | 0     | DAC A analog voltage output                                           |
| OUTB            | 7   | 0     | DAC B analog voltage output                                           |
| REF             | 6   | I     | Analog reference voltage input                                        |
| SCLK            | 2   | I     | Digital serial clock input                                            |
| V <sub>DD</sub> | 8   | Р     | Positive power supply                                                 |



# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

| Supply voltage (V <sub>DD</sub> to AGND)                         |                                                             |
|------------------------------------------------------------------|-------------------------------------------------------------|
| Reference input voltage range                                    | $\dots - 0.3 \text{ V to V}_{\text{DD}} + 0.3 \text{ V}$    |
| Digital input voltage range                                      | $\dots - 0.3 \text{ V to V}_{\text{DD}}^{} + 0.3 \text{ V}$ |
| Operating free-air temperature range, T <sub>A</sub> : TLV5617AC |                                                             |
| TLV5617AI                                                        | 40°C to 85°C                                                |
| Storage temperature range, T <sub>stg</sub>                      | –65°C to 150°C                                              |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds     |                                                             |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

|                                                     |                                    | MIN  | NOM   | MAX                  | UNIT |
|-----------------------------------------------------|------------------------------------|------|-------|----------------------|------|
|                                                     | $V_{DD} = 5 V$                     | 4.5  | 5     | 5.5                  | V    |
| Supply voltage, V <sub>DD</sub>                     | $V_{DD} = 3 V$                     | 2.7  | 3     | 3.3                  |      |
| Power on reset, POR                                 |                                    | 0.55 |       | 2                    | V    |
| High-level digital input voltage, VIH               | $V_{DD} = 2.7 V \text{ to } 5.5 V$ | 2    |       |                      | V    |
| Low-level digital input voltage, VIL                | $V_{DD} = 2.7 V \text{ to } 5.5 V$ |      |       | 0.8                  | V    |
| Reference voltage, V <sub>ref</sub> to REF terminal | $V_{DD} = 5 V$ (see Note 1)        | AGND | 2.048 | V <sub>DD</sub> -1.5 | V    |
| Reference voltage, V <sub>ref</sub> to REF terminal | $V_{DD} = 3 V$ (see Note 1)        | AGND | 1.024 | V <sub>DD</sub> -1.5 | V    |
| Load resistance, RL                                 |                                    | 2    |       |                      | kΩ   |
| Load capacitance, CL                                |                                    |      |       | 100                  | pF   |
| Clock frequency, fCLK                               |                                    |      |       | 20                   | MHz  |
| Operating free air temperature T                    | TLV5617AC                          | 0    |       | 70                   | °C   |
| Operating free-air temperature, T <sub>A</sub>      | TLV5617AI                          | -40  |       | 85                   | J    |

NOTE 1: Due to the x2 output buffer, a reference input voltage  $\geq (V_{DD}-0.4 \text{ V})/2$  causes clipping of the transfer function.



# electrical characteristics over recommended operating conditions (unless otherwise noted)

#### power supply

|                      | PARAMETER                     | TEST CONDITIONS                          |  | MIN | TYP | MAX | UNIT |
|----------------------|-------------------------------|------------------------------------------|--|-----|-----|-----|------|
| Power supply current |                               | No load, All inputs = AGND or $V_{DD}$ , |  |     | 1.7 | 2.5 | mA   |
| IDD                  | Power supply current          | DAC latch = 0x800                        |  |     | 0.7 | 1   | mA   |
|                      | Power down supply current     |                                          |  |     | 1   |     | μA   |
| PSRR                 | Dower evently rejection ratio | Zero scale, See Note 2                   |  |     | -65 |     | dB   |
| FORR                 | Power supply rejection ratio  | Full scale, See Note 3                   |  | -65 |     | uВ  |      |

NOTES: 2. Power supply rejection ratio at zero scale is measured by varying V<sub>DD</sub> and is given by:

 $PSRR = 20 \log \left[ (E_{ZS}(V_{DD}max) - E_{ZS}(V_{DD}min)/V_{DD}max) \right]$ 

3. Power supply rejection ratio at full scale is measured by varying V<sub>DD</sub> and is given by: PSRR = 20 log [(E<sub>G</sub>(V<sub>DD</sub>max) – E<sub>G</sub>(V<sub>DD</sub>min)/V<sub>DD</sub>max]

#### static DAC specifications

| PARAMETER                                     | TEST CONDITIONS                                                                                                                                                                  | MIN                                                                                                                                                                                                                 | TYP                                                                                                                                                                                                         | MAX                                                                                                                                                                                                                      | UNIT                                                                                                                                                                                                                                                         |
|-----------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Resolution                                    |                                                                                                                                                                                  | 10                                                                                                                                                                                                                  |                                                                                                                                                                                                             |                                                                                                                                                                                                                          | bits                                                                                                                                                                                                                                                         |
| Integral nonlinearity                         | See Note 4                                                                                                                                                                       |                                                                                                                                                                                                                     | ±0.7                                                                                                                                                                                                        | ±1                                                                                                                                                                                                                       | LSB                                                                                                                                                                                                                                                          |
| Differential nonlinearity                     | See Note 5                                                                                                                                                                       |                                                                                                                                                                                                                     | ±0.1                                                                                                                                                                                                        | ±1                                                                                                                                                                                                                       | LSB                                                                                                                                                                                                                                                          |
| Zero-scale error (offset error at zero scale) | See Note 6                                                                                                                                                                       |                                                                                                                                                                                                                     |                                                                                                                                                                                                             | ±12                                                                                                                                                                                                                      | mV                                                                                                                                                                                                                                                           |
| Zero-scale-error temperature coefficient      | See Note 7                                                                                                                                                                       |                                                                                                                                                                                                                     | 10                                                                                                                                                                                                          |                                                                                                                                                                                                                          | ppm/°C                                                                                                                                                                                                                                                       |
| Gain error                                    | See Note 8                                                                                                                                                                       |                                                                                                                                                                                                                     |                                                                                                                                                                                                             | ±0.6                                                                                                                                                                                                                     | % full<br>scale V                                                                                                                                                                                                                                            |
| Gain-error temperature coefficient            | See Note 9                                                                                                                                                                       |                                                                                                                                                                                                                     | 10                                                                                                                                                                                                          |                                                                                                                                                                                                                          | ppm/°C                                                                                                                                                                                                                                                       |
|                                               | Resolution     Integral nonlinearity     Differential nonlinearity     Zero-scale error (offset error at zero scale)     Zero-scale-error temperature coefficient     Gain error | ResolutionSee Note 4Integral nonlinearitySee Note 4Differential nonlinearitySee Note 5Zero-scale error (offset error at zero scale)See Note 6Zero-scale-error temperature coefficientSee Note 7Gain errorSee Note 8 | Resolution10Integral nonlinearitySee Note 4Differential nonlinearitySee Note 5Zero-scale error (offset error at zero scale)See Note 6Zero-scale-error temperature coefficientSee Note 7Gain errorSee Note 8 | Resolution10Integral nonlinearitySee Note 4±0.7Differential nonlinearitySee Note 5±0.1Zero-scale error (offset error at zero scale)See Note 62Zero-scale-error temperature coefficientSee Note 710Gain errorSee Note 810 | Resolution 10   Integral nonlinearity See Note 4 ±0.7 ±1   Differential nonlinearity See Note 5 ±0.1 ±1   Zero-scale error (offset error at zero scale) See Note 6 ±12   Zero-scale-error temperature coefficient See Note 7 10   Gain error See Note 8 ±0.6 |

NOTES: 4. The relative accuracy of integral nonlinearity (INL), sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale, excluding the effects of zero-code and full-scale errors.

5. The differential nonlinearity (DNL), sometimes referred to as differential error, is the difference between the measured and ideal 1-LSB amplitude change of any two adjacent codes.

6. Zero-scale error is the deviation from zero voltage output when the digital input code is zero.

Zero scale error temperature coefficient is given by: E<sub>ZS</sub> TC = [E<sub>ZS</sub> (T<sub>max</sub>) – E<sub>ZS</sub> (T<sub>min</sub>)]/2V<sub>ref</sub> × 10<sup>6</sup>/(T<sub>max</sub> – T<sub>min</sub>).
Gain error is the deviation from the ideal output (2V<sub>ref</sub> – 1 LSB) with an output load of 10 kΩ.
Gain temperature coefficient is given by: E<sub>G</sub> T<sub>C</sub> = [E<sub>G</sub> (T<sub>max</sub>) – E<sub>g</sub> (T<sub>min</sub>)]/2V<sub>ref</sub> × 10<sup>6</sup>/(T<sub>max</sub> – T<sub>min</sub>).

#### output specifications

|    | PARAMETER                       | TEST CONDITIONS                                           | MIN | TYP | MAX                  | UNIT |
|----|---------------------------------|-----------------------------------------------------------|-----|-----|----------------------|------|
| Vo | Output voltage range            | R <sub>L</sub> = 10 kΩ                                    |     |     | V <sub>DD</sub> -0.4 | V    |
|    | Output load regulation accuracy | $V_{O} = 4.096 V$ , 2.048 V R <sub>L</sub> = 2 k $\Omega$ |     |     | ±0.29                | % FS |

#### reference input

|    | PARAMETER                                                                         | TEST CONDITIONS                                                                                                                                                         |   |  | TYP                 | MAX | UNIT |
|----|-----------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---|--|---------------------|-----|------|
| VI | Input voltage range                                                               |                                                                                                                                                                         | 0 |  | V <sub>DD-1.5</sub> | V   |      |
| RI | Input resistance                                                                  |                                                                                                                                                                         |   |  | 10                  |     | MΩ   |
| Cl | Input capacitance                                                                 |                                                                                                                                                                         |   |  | 5                   |     | pF   |
|    |                                                                                   | $REF = 0.2  V_{pp} + 1.024  V  dc \qquad \qquad$ |   |  | 1.3                 |     | MHz  |
|    | Reference input bandwidth                                                         |                                                                                                                                                                         |   |  | 525                 |     | kHz  |
|    | Reference feedthrough REF = 1 V <sub>pp</sub> at 1 kHz + 1.024 V dc (see Note 10) |                                                                                                                                                                         |   |  | -80                 |     | dB   |

NOTE 10: Reference feedthrough is measured at the DAC output with an input code = 0x000.



# electrical characteristics over recommended operating conditions (unless otherwise noted) (Continued)

#### digital inputs

|                 | PARAMETER                        | TEST CONDITIONS      | MIN | TYP | MAX | UNIT |
|-----------------|----------------------------------|----------------------|-----|-----|-----|------|
| Чн              | High-level digital input current | $V_{I} = V_{DD}$     |     |     | 1   | μΑ   |
| Ι <sub>ΙL</sub> | Low-level digital input current  | V <sub>I</sub> = 0 V | -1  |     |     | μΑ   |
| Ci              | Input capacitance                |                      |     | 8   |     | pF   |

#### analog output dynamic performance

|                                                     | PARAMETER                          | TEST                                                                                                    | TEST CONDITIONS |                                                         |     | ТҮР | MAX  | UNIT |
|-----------------------------------------------------|------------------------------------|---------------------------------------------------------------------------------------------------------|-----------------|---------------------------------------------------------|-----|-----|------|------|
| t <sub>s(ES)</sub> Output settling time, full scale |                                    | $R_{I} = 10 \text{ k}\Omega, \qquad C_{I} = 100 \text{ p}$                                              |                 | Fast                                                    | 2.5 |     |      |      |
| <sup>t</sup> s(FS)                                  | Ouput setting time, full scale     | See Note 11                                                                                             |                 | Slow                                                    |     | 12  |      | μs   |
| + (22)                                              | Output pattling time, and to and   |                                                                                                         |                 | Fast                                                    |     | 1   |      |      |
| <sup>t</sup> s(CC)                                  | Output settling time, code to code |                                                                                                         |                 | Slow                                                    |     | 2   |      | μs   |
| SR SI                                               | Slew rate                          | $R_L = 10 \text{ k}\Omega$ , $C_L = 100 \text{ pF}$ , Fas                                               | Fast            |                                                         | 3   |     | V/µs |      |
| SK                                                  | Siewrate                           | See Note 13                                                                                             | Slow            |                                                         | 0.5 |     | v/µs |      |
|                                                     | Glitch energy                      | $\frac{\text{DIN}}{\text{CS}} = 0 \text{ to } 1,$                                                       | FCLK = 100 kHz, |                                                         |     | 5   |      | nV–s |
| SNR                                                 | Signal-to-noise ratio              |                                                                                                         |                 |                                                         |     | 56  |      |      |
| SINAD                                               | Signal-to-noise + distortion       | $f_{s} = 102 \text{ kSPS}, f_{out} = 1 \text{ kHz},$<br>R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 100 pF |                 | $f_s = 102 \text{ kSPS}, f_{out} = 1 \text{ kHz},$      |     | 55  |      | dB   |
| THD                                                 | Total harmonic distortion          |                                                                                                         |                 | $R_L = 10 \text{ k}\Omega, \qquad C_L = 100 \text{ pF}$ |     | -62 |      | uБ   |
| SFDR                                                | Spurious free dynamic range        |                                                                                                         |                 |                                                         | 64  |     |      |      |

NOTES: 11. Settling time is the time for the output signal to remain within  $\pm 0.5$  LSB of the final measured value for a digital input code change of 0x020 to 0xFDC and 0xFDC to 0x020 respectively. Not tested, assured by design.

12. Settling time is the time for the output signal to remain within ± 0.5 LSB of the final measured value for a digital input code change of one count. Not tested, assured by design.

13. Slew rate determines the time it takes for a change of the DAC output from 10% to 90% of full-scale voltage.



# digital input timing requirements

|                         |                                                                       | MIN | NOM | MAX | UNIT |
|-------------------------|-----------------------------------------------------------------------|-----|-----|-----|------|
| <sup>t</sup> su(CS–CK)  | Setup time, CS low before first negative SCLK edge                    | 10  |     |     | ns   |
| <sup>t</sup> su(C16-CS) | Setup time, 16 <sup>th</sup> negative SCLK edge before CS rising edge | 10  |     |     | ns   |
| t <sub>wH</sub>         | SCLK pulse width high                                                 | 25  |     |     | ns   |
| t <sub>wL</sub>         | SCLK pulse width low                                                  | 25  |     |     | ns   |
| <sup>t</sup> su(D)      | Setup time, data ready before SCLK falling edge                       | 10  |     |     | ns   |
| <sup>t</sup> h(D)       | Hold time, data held valid after SCLK falling edge                    | 5   |     |     | ns   |

# timing requirements

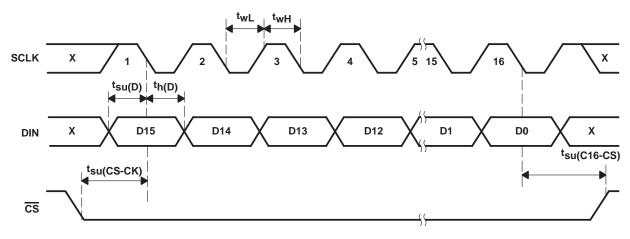
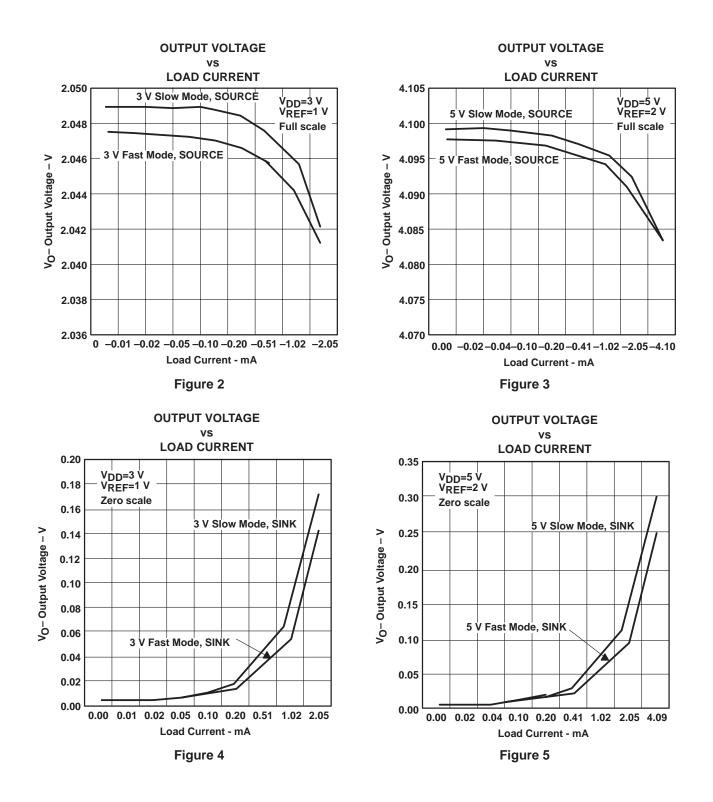


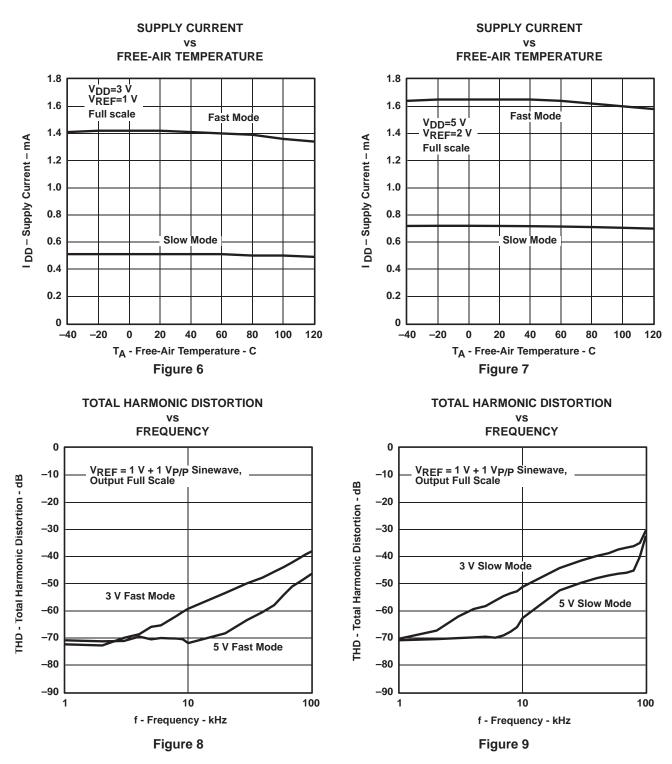
Figure 1. Timing Diagram



# **TYPICAL CHARACTERISTICS**



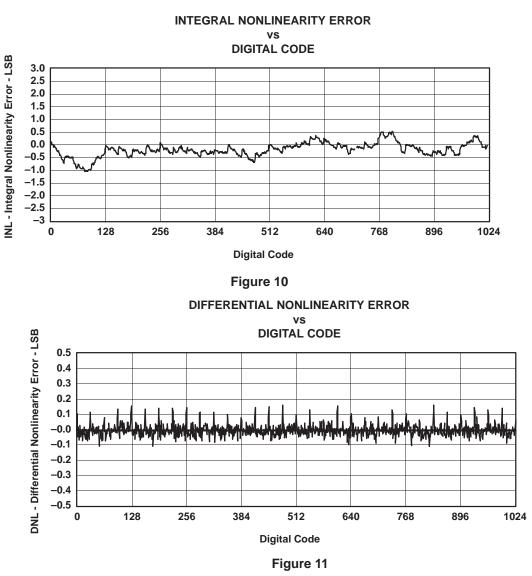




# **TYPICAL CHARACTERISTICS**



# **TYPICAL CHARACTERISTICS**





# **APPLICATION INFORMATION**

# general function

The TLV5617A is a dual 10-bit, single-supply DAC, based on a resistor-string architecture. It consists of a serial interface, a speed and power-down control logic, a resistor string, and a rail-to-rail output buffer.

The output voltage (full scale determined by the reference) is given by:

2 REF 
$$\frac{\text{CODE}}{0x1000}$$
 [V]

Where REF is the reference voltage and CODE is the digital input value in the range 0x000 to 0xFFC. A power-on reset initially puts the internal latches to a defined state (all bits zero).

#### serial interface

A falling edge of  $\overline{CS}$  starts shifting the data bit-per-bit (starting with the MSB) to the internal register on the falling edges of SCLK. After 16 bits have been transferred or  $\overline{CS}$  rises, the content of the shift register is moved to the target latches (DAC A, DAC B, BUFFER, CONTROL), depending on the control bits within the data word.

Figure 12 shows examples of how to connect the TLV5617A to TMS320, SPI™, and Microwire™.

| TMS320  | TLV5617A | SPI  | TLV5617A | Microwire | TLV5617A |
|---------|----------|------|----------|-----------|----------|
| DSP FSX |          | I/O  |          | I/O -     |          |
| DX DX   | DIN      | MOSI | DIN DIN  | so –      | DIN      |
| СГКХ —  | SCLK     | scк  | SCLK     | SK –      | SCLK     |

#### Figure 12. Three-Wire Interface

Notes on SPI<sup> $\mathbb{M}$ </sup> and Microwire<sup> $\mathbb{M}$ </sup>: Before the controller starts the data transfer, the software has to generate a falling edge on the pin connected to  $\overline{CS}$ . If the word width is 8 bits (SPI<sup> $\mathbb{M}$ </sup> and Microwire<sup> $\mathbb{M}$ </sup>) two write operations must be performed to program the TLV5617A. After the write operation(s), the holding registers or the control register are updated automatically on the 16<sup>th</sup> positive clock edge.

# serial clock frequency and update rate

The maximum serial clock frequency is given by:

$$f_{sclkmax} = \frac{1}{t_{whmin} + t_{wlmin}} = 20 \text{ MHz}$$

The maximum update rate is:

$$f_{updatemax} = \frac{1}{16 \ \left( t_{whmin} + t_{wlmin} \right)} = 1.25 \ \text{MHz}$$

Note that the maximum update rate is just a theoretical value for the serial interface, as the settling time of the TLV5617A should also be considered.



# **APPLICATION INFORMATION**

# data format

The 16-bit data word for the TLV5617A consists of two parts:

- Program bits (D15..D12)
- New data (D11..D0)

| D15 | D14 | D13 | D12 | D11 | D10              | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
|-----|-----|-----|-----|-----|------------------|----|----|----|----|----|----|----|----|----|----|
| R1  | SPD | PWR | R0  | MSB | 12 Data bits LSB |    |    |    |    |    |    |    | 0  | 0  |    |

SPD: Speed control bit $1 \rightarrow$  fast mode $0 \rightarrow$  slow modePWR: Power control bit $1 \rightarrow$  power down $0 \rightarrow$  normal operationOn power up, SPD and PWD are reset to 0 (slow mode and normal operation)

The following table lists all possible combination of register-select bits:

#### register-select bits

| R1 | R0 | REGISTER                                                 |
|----|----|----------------------------------------------------------|
| 0  | 0  | Write data to DAC B and BUFFER                           |
| 0  | 1  | Write data to BUFFER                                     |
| 1  | 0  | Write data to DAC A and update DAC B with BUFFER content |
| 1  | 1  | Reserved                                                 |

The meaning of the 12 data bits depends on the register. If one of the DAC registers or the BUFFER is selected, then the 12 data bits determine the new DAC value:

# examples of operation

• Set DAC A output, select fast mode:

Write new DAC A value and update DAC A output:

| D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8  | D7      | D6        | D5   | D4 | D3 | D2 | D1 | D0 |
|-----|-----|-----|-----|-----|-----|----|-----|---------|-----------|------|----|----|----|----|----|
| 1   | 1   | 0   | 0   |     |     |    | Nev | v DAC A | output va | alue |    |    |    | 0  | 0  |

The DAC A output is updated on the rising clock edge after D0 is sampled.

• Set DAC B output, select fast mode:

Write new DAC B value to BUFFER and update DAC B output:

| D15 | D14 | D13 | D12 | D11 | D10                                       | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
|-----|-----|-----|-----|-----|-------------------------------------------|----|----|----|----|----|----|----|----|----|----|
| 0   | 1   | 0   | 0   |     | New BUFFER content and DAC B output value |    |    |    |    |    |    |    |    | 0  | 0  |

The DAC A output is updated on the rising clock edge after D0 is sampled.

• Set DAC A value, set DAC B value, update both simultaneously, select slow mode:

1. Write data for DAC B to BUFFER:

| D15 | D14 | D13 | D12 | D11 | D10             | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
|-----|-----|-----|-----|-----|-----------------|----|----|----|----|----|----|----|----|----|----|
| 0   | 0   | 0   | 1   |     | New DAC B value |    |    |    |    |    |    |    | 0  | 0  |    |

#### 2. Write new DAC A value and update DAC A and B simultaneously:

|   | D15 | D14 | D13 | D12 | D11 | D10             | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
|---|-----|-----|-----|-----|-----|-----------------|----|----|----|----|----|----|----|----|----|----|
| I | 1   | 0   | 0   | 0   |     | New DAC A value |    |    |    |    |    |    |    |    | 0  | 0  |



# **APPLICATION INFORMATION**

# examples of operation (continued)

Both outputs are updated on the rising clock edge after D0 from the DAC A data word is sampled.

• Set powerdown mode:

| D15 | D14 | D13 | D12 | D11 | D10 | D9 | D8 | D7 | D6 | D5 | D4 | D3 | D2 | D1 | D0 |
|-----|-----|-----|-----|-----|-----|----|----|----|----|----|----|----|----|----|----|
| Х   | Х   | 1   | Х   | Х   | Х   | Х  | Х  | Х  | Х  | Х  | Х  | Х  | Х  | Х  | Х  |

X = Don't care

#### linearity, offset, and gain error using single ended supplies

When an amplifier is operated from a single supply, the voltage offset can still be either positive or negative. With a positive offset, the output voltage changes on the first code change. With a negative offset, the output voltage may not change with the first code, depending on the magnitude of the offset voltage.

The output amplifier attempts to drive the output to a negative voltage. However, because the most negative supply rail is ground, the output cannot drive below ground and clamps the output at 0 V.

The output voltage then remains at zero until the input code value produces a sufficient positive output voltage to overcome the negative offset voltage, resulting in the transfer function shown in Figure 13.

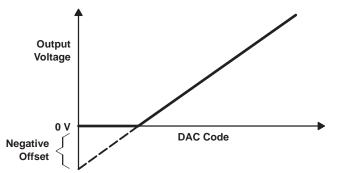


Figure 13. Effect of Negative Offset (Single Supply)

This offset error, not the linearity error, produces this breakpoint. The transfer function would have followed the dotted line if the output buffer could drive below the ground rail.

For a DAC, linearity is measured between zero-input code (all inputs 0) and full-scale code (all inputs 1) after offset and full scale are adjusted out or accounted for in some way. However, single supply operation does not allow for adjustment when the offset is negative due to the breakpoint in the transfer function. So the linearity is measured between full-scale code and the lowest code that produces a positive output voltage.

# definitions of specifications and terminology

# integral nonlinearity (INL)

The relative accuracy or integral nonlinearity (INL), sometimes referred to as linearity error, is the maximum deviation of the output from the line between zero and full scale excluding the effects of zero code and full-scale errors.

# differential nonlinearity (DNL)

The differential nonlinearity (DNL), sometimes referred to as differential error, is the difference between the measured and ideal 1 LSB amplitude change of any two adjacent codes. Monotonic means the output voltage changes in the same direction (or remains constant) as a change in the digital input code.



# definitions of specifications and terminaology (continued)

#### zero-scale error (E<sub>ZS</sub>)

Zero-scale error is defined as the deviation of the output from 0 V at a digital input value of 0.

# gain error (E<sub>G</sub>)

Gain error is the error in slope of the DAC transfer function.

#### total harmonic distortion (THD)

THD is the ratio of the rms value of the first six harmonic components to the value of the fundamental signal. The value for THD is expressed in decibels.

#### signal-to-noise ratio + distortion (S/N+D)

S/N+D is the ratio of the rms value of the output signal to the rms sum of all other spectral components below the Nyquist frequency, including harmonics but excluding dc. The value for S/N+D is expressed in decibels.

# spurious free dynamic range (SFDR)

Spurious free dynamic range is the difference between the rms value of the output signal and the rms value of the largest spurious signal within a specified bandwidth. The value for SFDR is expressed in decibels.

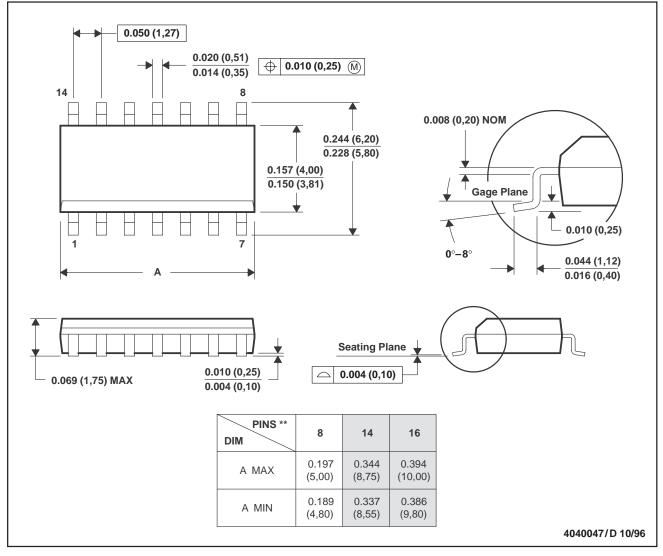


# **MECHANICAL DATA**

# D (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE





NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012



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